

规格书编号

SPEC NO:

产品规格书 SPECIFICATION

CUSTOMER 客 户:						
PRODUCT 产品:	SAW FILTER					
MODEL NO 型 号:	HDF823A-F11					
PREPARED 编 制:	CHECKED 审 相	亥:				
APPROVED 批准:	РАТЕ 日 其	月:2006-5-11				
客户确认 CUSTOMER RECEIVED:						
审核 CHECKED	批准 APPROVED	日期 DATE				

无锡市好达电子有限公司 Shoulder Electronics Limited



SAW FILTER HDF823A-F11

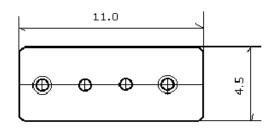
更改历史记录 History Record

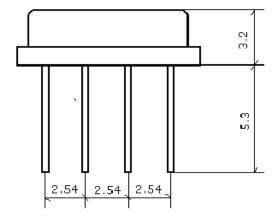
更改日期 Date	规格书编号 Spec. No.	产品型号 Part No.	客户产品型号 Customer No.	更改内容描述 Modify Content	备注 Remark

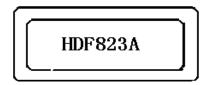


1. Package Dimension

Unit:mm







2. Marking HD F823A

2.1 Color: Black or Blue

2.2 823: Center Frequency(MHz)

3. Performance

3.1Application

Low-Loss SAW Filter of cordless system.

Center Frequency:823MHz

3.2Maximum Rating

Operation Temperature Range	-40°C to +85°C
Storage Temperature Range	-40°C to +85°C
DC. Voltage	10 V
Maximum Input Power	5 dBm

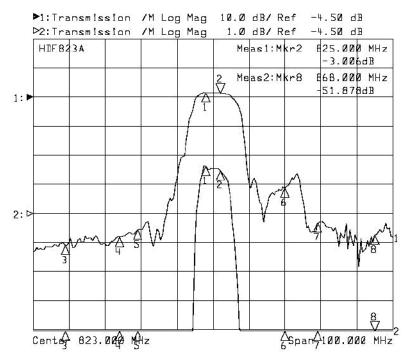


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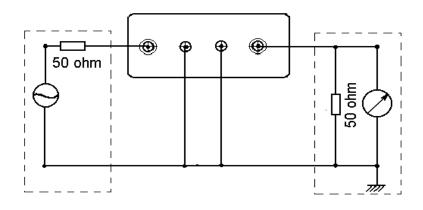
3.3 Electronic Characteristics

Item	Specification	
Center Frequency(fo)	823 MHz	
Insertion Loss(dB)		
1.821-825 MHz	4.5max	
2.)772-782 MHz	40 min	
3.)797-802 MHz	30 min	
4.)843-852 MHz	20 min	
5.)868~902MHz	40 min	
Ripple deviation (821-825MHz)(dB)	1.5max	
Input/output Impedance(Nominal)	50 Ω	

3.4 Frequency Characteristics



3.5 Test Circuit



SAW FILTER HDF823A-F11

4. ENVIRONMENTAL CHARACTERISTICS

4-1 High temperature exposure

Subject the device to $+85^{\circ}$ C for 16 hours. Then release the filter into the room conditions for 24 hours prior to the measurement. It shall fulfill the specifications in 3.3.

4-2 Low temperature exposure

Subject the device to -40° C for 16 hours. Then release the device into the room conditions for 24 hours prior to the measurement. It shall fulfill the specifications in 3.3.

4-3 Temperature cycling

Subject the device to a low temperature of -40° C for 30 minutes. Following by a high temperature of $+80^{\circ}$ C for 30 Minutes. Then release the device into the room conditions for 24 hours prior to the measurement. It shall meet the specifications in 3.3.

4-4 Resistance to solder heat

Dip the device terminals no closer than 1.5mm into the solder bath at 260° C $\pm 10^{\circ}$ C for 10 ± 1 sec. Then release the device into the room conditions for 4 hours. The device shall meet the specifications in 3.3.

4-5 Solderability

Subject the device terminals into the solder bath at 245° C $\pm 5^{\circ}$ C for 5s, More than 95% area of the terminals must be covered with new solder. It shall meet the specifications in 3.3.

4-6 Mechanical shock

Drop the device randomly onto the concrete floor from the height of 1m 3 times. the device shall fulfill the specifications in 3.3.

4-7 Vibration

Subject the device to the vibration for 1 hour each in x,y and z axes with the amplitude of 1.5 mm at 10 to 55 Hz. The device shall fulfill the specifications in 3.3.

5. REMARK

5.1 Static voltage

Static voltage between signal load & ground may cause deterioration &destruction of the component. Please avoid static voltage.

5.2 Ultrasonic cleaning

Ultrasonic vibration may cause deterioration & destruction of the component. Please avoid ultrasonic cleaning

5.3 Soldering

Only leads of component may be soldered . Please avoid soldering another part of component.